Bolometry using high sensitivity NTD germanium thermometers

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Physical Laboratory



Introduction





Bolometers

A bolometer is conceptually very simple



Absorber temperature is a function of "optical" power

Nearly flat spectral response over wide bandwidth:

Can define bandwidth using filters/waveguides

Can use simple read-out scheme

Practical to calibrate





Calorimeters

Measure temperature as a function of time and you have a calorimeter



YSGOL

Time

Uses include: Detecting: X-rays Dark matter Double beta decay Mass spectroscopy



Sub-mm astronomy

Astronomy at wavelengths of a few hundred μm Typically around 450 and 850 μm

Bolometers are the best detectors for continuum ("broadband") measurements









Bolometers for sub-mm astronomy

"Classical" design for sub-mm: Metal-coated dielectric as absorber Semiconductor resistance thermometer

Each pixel illuminated by a feedhorn

Build up focal plane by stacking individual pixels together, each with independent readout



Operate at 100 mK or 300 mK



Readout circuit





NTD Germanium





Neutron transmutation doping

NTD relies on elements having mix of isotopes; some transmute to acceptor and donor elements in neutron flux

Since isotope distribution is homogenous, doping is uniform and random down to the atomic level

NTD silicon ~ 5% of silicon semiconductor market Used mainly for power transistors

NTD Ge: made in much smaller quantities; applications more limited – available commercially from Haller-Beeman Associates (http://www.haller-beeman.com/)





NTD Germanium

Neutron transmutation doping converts 70 Ge to 71 Ga (acceptor) and 74 Ge to 75 As (donor)

Doping level depends on neutron flux

Compensation ratio can be changed by altering isotope ratios Very simple R(T) relation – no Chebychev polynomials!





VRH

The low temperature conduction method is variable range hopping (VRH). This requires an amorphous structure.

For NTD Ge, the crystal is uniform but the dopant atom positions are random (compare with NbSi which is an amorphous alloy)

Need extremely uniform doping for reproducible behaviour. Other doping methods cannot achieve this





Bolometers

NTD Ge meets all the requirements for cryogenic bolometers and calorimeters:

High sensitivity to temperature – can be tuned for operating temperature from < 20 mK to 4 K

Very good reproducibility (so instruments remain calibrated) Low "excess" noise

Good (metallic) electrical contacts can be made readily

Can be made very small (-> low heat capacity)





Spiderweb bolometer

Developed at Caltech Thermistor sits at centre of silicon nitride mesh spiderweb absorber







Array made of individual pixels

JPL NTD germanium spiderweb bolometer module with Cardiff feedhorn and metal mesh filter (HFI)



SCUBA bolometer array







Many pixels on single wafer



Wafer for SPIRE bolometer array





Ge chips stuck on by hand

array

SPIRE bolometer



Some instruments using NTD Ge

Astronomy

SCUBA HFI SPIRE Boomerang Bolocam

Dark matter

Eidelweiss CDMS



Double beta decay CUORE



Competing technologies

Ion implanted silicon

- + Similar properties to NTD Ge very uniform doping
- + Easier to make arrays (no manual steps)
- Traditionally 1/f noise has been a severe problem
 Mitigated by increasing doping thickness
- Not usually used for thermometry

Transition edge sensors

- + Easier to make arrays, multiplexing is practical
- + Better sensitivity
- Stop working completely if optical signal too large
- Read-out much more complex
- Sensitive to magnetic fields
- Don't make good thermometers!

History of ground based sub-mm bolometer arrays



2004-





Ge

Number of pixels

Material







R(T) expressions

18

VRH

Use NTD Ge on the insulator side of the metal-insulator transition

Conduction is via variable range hopping (VRH) – electrons hop to sites with small ΔE rather than nearest neighbour

For NTD Ge, people normally assume

$$R = R^* \exp \sqrt{\frac{T_g}{T}}$$



R: resistance *T*: temperature *R*^{*}, T_g: constants



Analytical expressions

Why is a simple analytical expression so useful?

Convenience: don't have to fit complex empirical functions (e.g. Chebychev polynomials)

Improves calibration accuracy – structure in residuals for empirical fits cause systematic errors, especially when measuring very small temperature differences.



0.01

Thermal conductance calculated from small temperature differences using NTD Ge (□) and RuO (o) thermometers



Analytical expressions

Why is a simple analytical expression so useful?

Need fewer points for calibration

Makes measurement errors more obvious – if you depart from the fit, perhaps something is wrong

Makes bolometer models simpler and enables analytical expressions to be written down for properties such as responsivity

Can even extrapolate fits outside range used for calibration with some degree of confidence, especially if using several thermometers from the same batch





VRH

But:

If you use the wrong expression, you make things worse!

In fact, theory suggests $R = R^* \exp\left(\frac{T_g}{T}\right)^p \rho \sim 0.5$

Or rather
$$R = R^* T^q \exp\left(\frac{T_g}{T}\right)^p$$
 $q = ???$

But we shall ignore *q* because experimentally it can generally be absorbed into the *p* term





Reasonable fit with p=0.5 to data for a 100 mK thermometer...



...but look at residuals. (And you should always look at residuals!)





Fit is now accurate to better than 0.5% in temperature over almost entire range



More measurements

Get similar results from examining other thermometers: but get different values of p



Check

Same thermistor measured in two entirely independent systems (on two different continents)

Other checks confirm results and suggest we really are measuring power-laws (difficult)



 $p(T_g)$

New measurements at lower T_g fall on this line!



· *'g*)

New measurements at lower T_g fall on this line! Barucci et al. Physica B 368 (2005) 139-142



But...

However, need to treat these values of p with some caution



Alternative expression

We can get good fits by letting *p* vary

McCammon finds this method does *not* work for ion implanted silicon, and suggests a modified equation with no new free parameters: ("Wouter" function)

$$R = R^* \exp \sqrt{\frac{T_g}{T}} + R^{*'} \exp \sqrt{\frac{T_g'}{T}}$$
$$R^{*'} = R^* \exp \left(2.522T_g^{(-0.25)} - 8.733\right)$$
$$T_g' = 2.7148T_g + 1.2328$$

D. McCammon, in Cryogenic Particle Detection, Ed. Enss, Springer 2005

D. McCammon, http://arxiv.org/abs/phy sics/0503086



He also finds this works well for an NTD Ge sample



Doesn't work well for 100 mK thermometer measurements





Astronomy,

Group

Instrumentation

... or for 300 mK thermometers





Astronomy

Group

Instrumentation

... or for measurements in Barucci et al 2005

VERSITY

IFYSGOL



NTD Ge sample from McCammon 2005



"Wouter" function fits the data well



Trying alternative expression But variable p fit is also good (at the expense of an extra free parameter)



Alternative expression

"Wouter" function seems to do a somewhat better job, but variable *p* fit is not bad



p(| _g)

Return to p as a function of T_q



Result from McCammon sample not wildly in disagreement. Hard to put error bar on – depends on systematic effects



$p(T_g)$

But: measurements on *bolometers* do not agree with the fit! Mounting in a bolometer shouldn't make a difference Only significant difference is geometry: contacts on one face not opposite sides – could this make a difference?



Conclusions

Neutron transmutation doped germanium can be used to make sensitive and reproducible thermometers with a very simple calibration.

This makes them ideal for use in bolometers and calorimeters

The commonly used calibration expression is often wrong, but adding one more parameter (p) produces good fits for all thermistors examined. There *may* be a correlation between p and T_q – more work is required!

The calibration expression proposed by McCammon based on work on silicon thermistors does *not* appear to be generally appropriate for NTD Ge.



More information: *Woodcraft et al. Journal of Low Temp. Physics 134* 925-944 (2004) <u>http://reference.lowtemp.org/woodcraft_ntd.pdf</u>